NSN 5962-01-371-6294

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+125.0 degrees celsius
End Application:
Pacer dawn
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Criticality Code Justification:
Feat
Case Outline Source And Designator:
D-10 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital, monolithic 256k (32k x 8-bit) cmos, static random access memory (sram)
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
45.00 nanoseconds propagation delay time, low to high level output and 45.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Ram
Special Features:
Esd
Terminal Type And Quantity:
28 pin
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig:
A458a0